



STTA3006CW/CP

TURBOSWITCH™ ULTRA-FAST HIGH VOLTAGE DIODES

MAIN PRODUCT CHARACTERISTICS

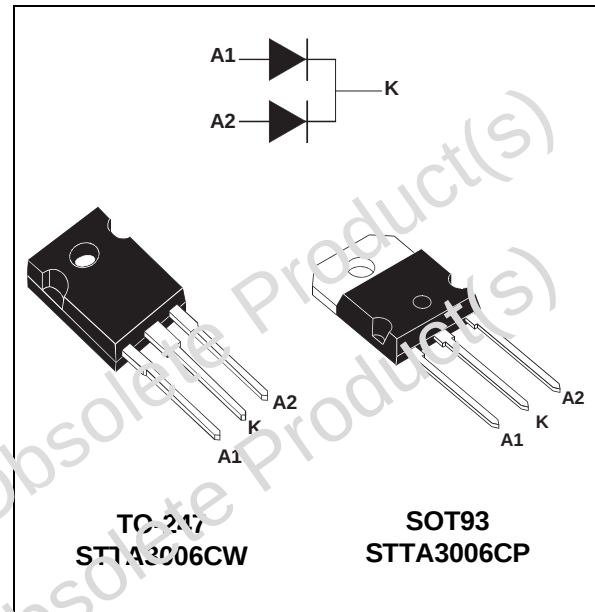
$I_{F(AV)}$	2 x 15A
V_{RRM}	600V
t_{rr} (typ)	35ns
V_F (max)	1.6V

FEATURES AND BENEFITS

- SPECIFIC TO "FREEWHEEL MODE" OPERATIONS: FREEWHEEL OR BOOSTER DIODE.
- ULTRA-FAST AND SOFT RECOVERY.
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR.
- HIGH FREQUENCY OPERATIONS.

DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes from 600V to 1200V. TURBOSWITCH family, drastically cuts losses in both the diode and the associated switching IGBT or MOSFET in all "freewheel mode" operations and is particularly suitable and efficient in motor



control freewheel applications and in booster diode applications in power factor control circuitries. Packaged either in TO-247 or SOT93, these 600V devices are particularly intended for use on 240V domestic mains.

ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		600	V
V_{RSM}	Non repetitive peak reverse voltage		600	V
$I_{F(RMS)}$	RMS forward current		30	A
I_{FRM}	Repetitive peak forward current	$t_p = 5 \mu s$ F = 5kHz square	200	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10$ ms sinusoidal	230	A
T_j	Maximum operating junction temperature		150	°C
T_{stg}	Storage temperature range		-65 to 150	°C

TM : TURBOSWITCH is a trademark of STMicroelectronics

STTA3006CW/CP**THERMAL AND POWER DATA**

Symbol	Parameter	Test conditions	Value	Unit
$R_{th(j-c)}$	Junction to case	Per diode Total Coupling	1.9 1.0 0.1	°C/W
P_1	Conduction power dissipation	Per diode $I_{F(AV)} = 30A$ $\delta = 0.5$ $T_c = 110^\circ C$	20.5	W
P_{max}	Total power dissipation $P_{max} = P_1 + P_3$ ($P_3 = 10\% P_1$)	Per diode $T_c = 105^\circ C$	22.5	W

STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
V_F^*	Forward voltage drop	$I_F = 15A$ $T_j = 25^\circ C$ $T_j = 125^\circ C$		1.3	1.8 1.6	V V
I_R^{**}	Reverse leakage current	$V_R = 0.8 \times V_{RRM}$ $T_j = 25^\circ C$ $T_j = 125^\circ C$		2	100 5	μA mA
V_{to}	Threshold voltage	$I_p < 3 \cdot I_{AV}$ $T_j = 125^\circ C$			1.06	V
r_d	Dynamic resistance				177	m Ω

Test pulse : * $t_p = 380 \mu s$, $\delta < 2\%$ ** $t_p = 5 ms$, $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = V_{to} \times I_{F(AV)} + r_d \times I_F^2 (RMS)$$

DYNAMIC ELECTRICAL CHARACTERISTICS (per diode)**TURN-OFF SWITCHING**

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{rr}	Reverse recovery time	$T_j = 25^\circ C$ $I_F = 0.5 A$ $I_R = 1A$ $I_{rr} = 0.25A$ $I_F = 1A$ $di_F/dt = -50A/\mu s$ $V_R = 30V$		35	65	ns
I_{RM}	Maximum reverse recovery current	$T_j = 125^\circ C$ $V_R = 400V$ $I_F = 15A$ $di_F/dt = -120 A/\mu s$ $di_F/dt = -500 A/\mu s$		17.5	12.5	A
S factor	Softness factor	$T_j = 125^\circ C$ $V_R = 400V$ $I_F = 15A$ $di_F/dt = -500 A/\mu s$		0.5		/

TURN-ON SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{fr}	Forward recovery time	$T_j = 25^\circ C$ $I_F = 15A$, $di_F/dt = 120 A/\mu s$ measured at, $1.1 \times V_{Fmax}$			500	ns
V_{Fp}	Peak forward voltage	$T_j = 25^\circ C$ $I_F = 15A$, $di_F/dt = 120 A/\mu s$			9	V

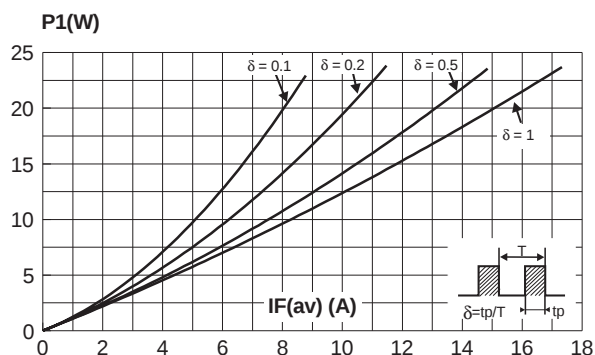
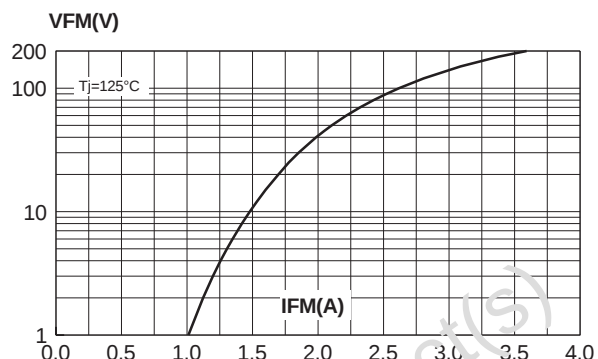
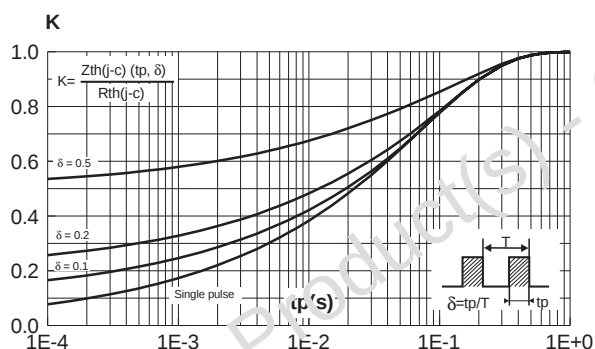
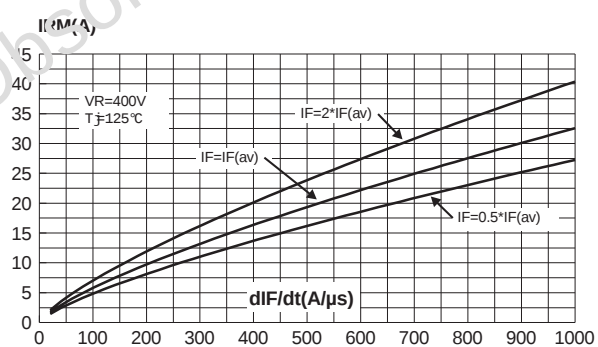
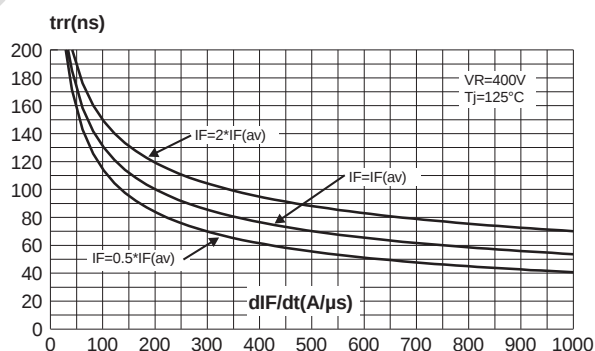
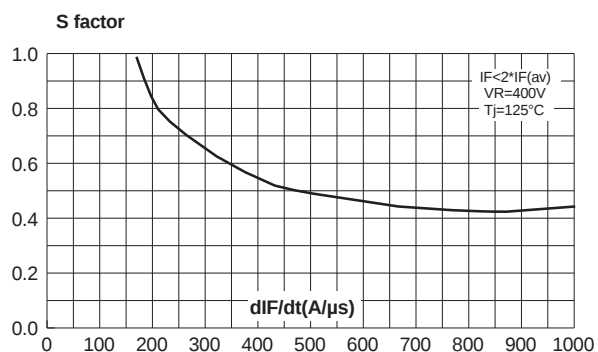
Fig. 1: Conduction losses versus average current.**Fig. 2:** Forward voltage drop versus forward current (maximum values).**Fig. 3:** Relative variation of thermal transient impedance junction to case versus pulse duration.**Fig. 4:** Peak reverse recovery current versus dIF/dt (90% confidence).**Fig. 5:** Reverse recovery time versus dIF/dt (90% confidence).**Fig. 6:** Softness factor (tb/ta) versus dIF/dt (typical values).

Fig. 7: Relative variation of dynamic parameters versus junction temperature (reference $T_J=125^{\circ}\text{C}$).

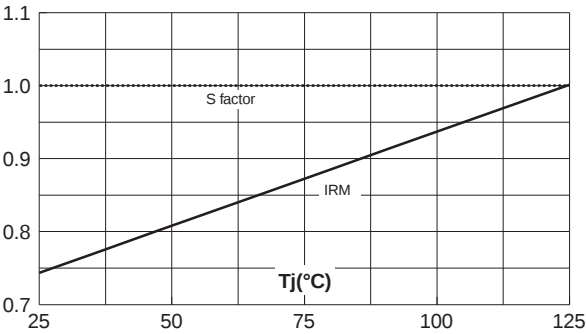


Fig. 8: Transient peak forward voltage versus dI_F/dt (90% confidence).

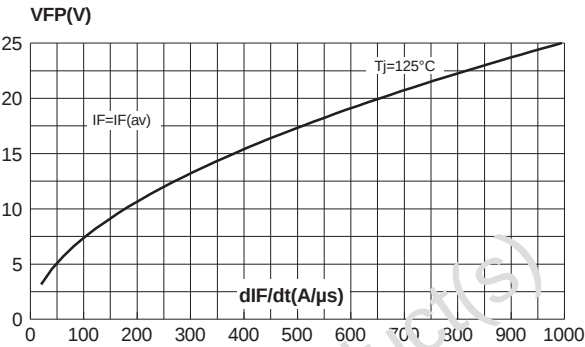
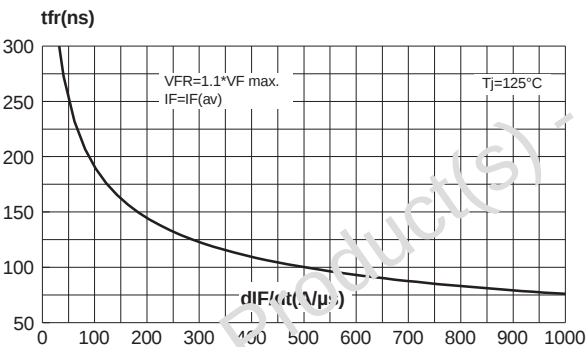


Fig. 9: Forward recovery time versus dI_F/dt (90% confidence).



APPLICATION DATA

The TURBOSWITCH is especially designed to provide the lowest overall power losses in any "FREEWHEEL Mode" application (Fig.A) considering both the diode and the companion

transistor, thus optimizing the overall performance in the end application. The way of calculating the power losses is given below:

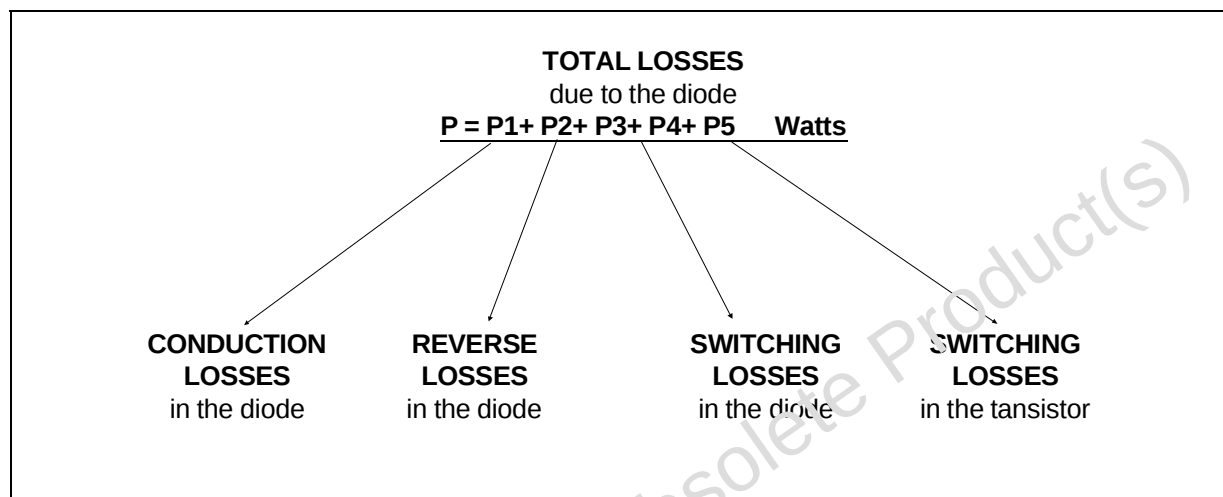
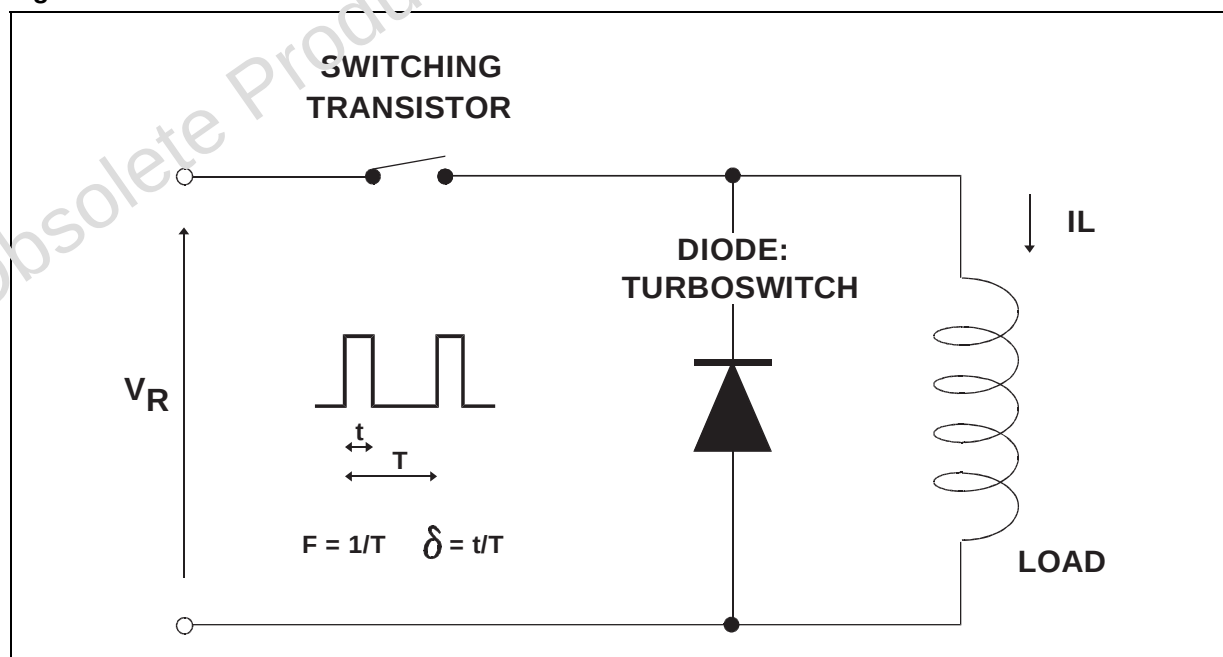
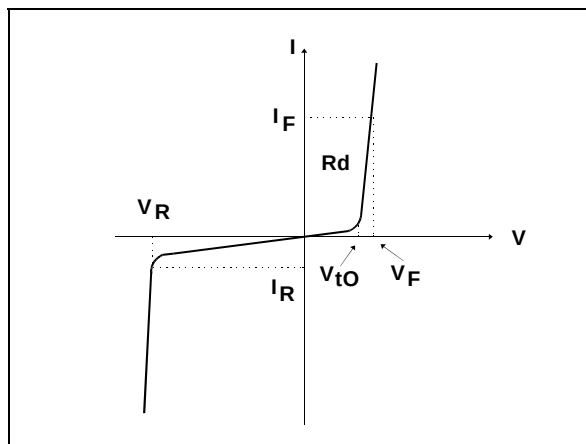


Fig. A : "FREEWHEEL" MODE



APPLICATION DATA (Cont'd)

Fig. B: STATIC CHARACTERISTICS



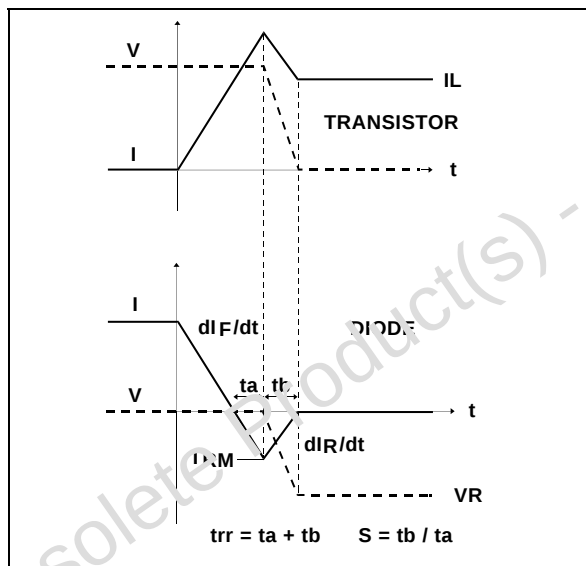
Conduction losses :

$$P1 = V_{t0} \cdot I_F(AV) + R_d \cdot I_F^2(RMS)$$

Reverse losses :

$$P2 = V_R \cdot I_R \cdot (1 - \delta)$$

Fig. C: TURN-OFF CHARACTERISTICS



Turn-on losses :

(in the transistor, due to the diode)

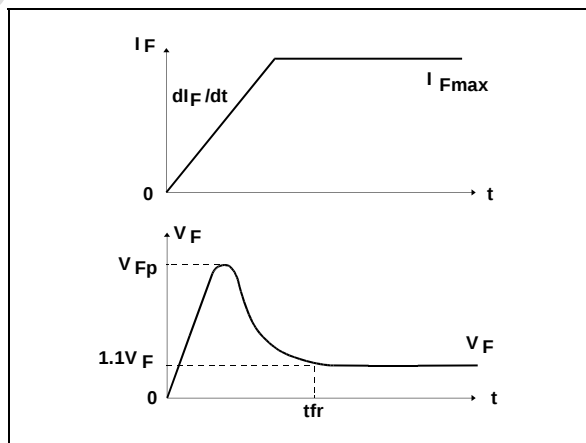
$$P5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dI_F/dt} + \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \times dI_F/dt}$$

Turn-off losses (in the diode) :

$$P3 = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt}$$

P3 and P5 are suitable for power MOSFET and IGBT

Fig. C: TURN-ON CHARACTERISTICS

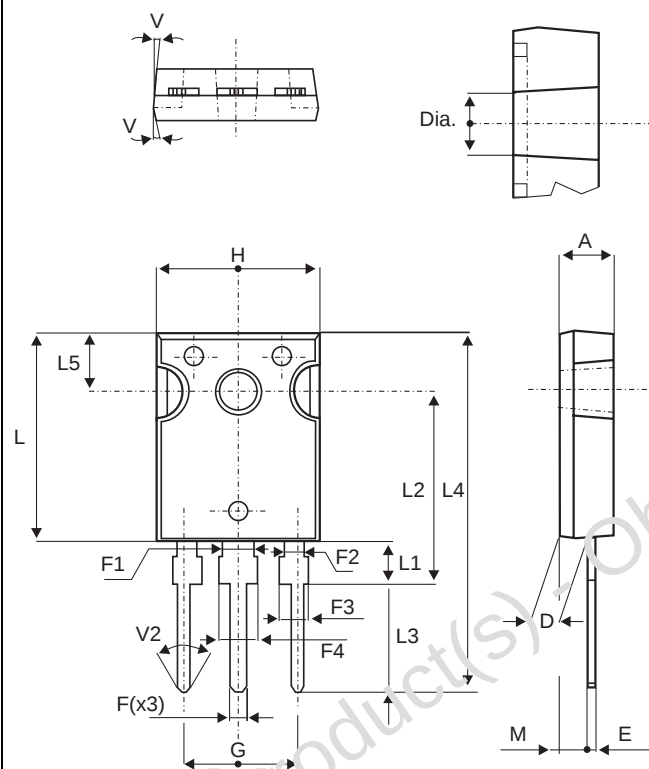


Turn-on losses :

$$P4 = 0.4 (V_{FP} - V_F) \cdot I_{Fmax} \cdot t_{fr} \cdot F$$

PACKAGE DATA

TO-247 Plastic



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.85		5.15	0.191		0.203
D	2.20		2.60	0.086		0.102
E	0.40		0.80	0.015		0.031
F	1.00		1.40	0.039		0.055
F1		3.00		0.118		
F2		2.00		0.078		
F3	2.00		2.40	0.078		0.094
F4	3.00		3.40	0.118		0.133
G		10.90		0.429		
H	15.45		15.75	0.608		0.620
L	19.85		20.15	0.781		0.793
L1	3.70		4.30	0.145		0.169
L2		18.50		0.728		
L3	14.20		14.80	0.559		0.582
L4		34.60		1.362		
L5		5.50		0.216		
M	2.00		3.00	0.078		0.118
V		5°		5°		
V2		60°		60°		
Dia.	3.55		3.65	0.139		0.143

- Cooling method : by conduction (C).
- Recommended torque value : 0.8 m.N
- Maximum torque value : 1 m.N

STTA3006CW/CP

PACKAGE DATA

SOT93 Plastic

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.70		4.90	1.185		0.193
C	1.90		2.10	0.075		0.083
D		2.50			0.098	
D1		2.00			0.078	
E	0.50		0.78	0.020		0.031
F	1.10		1.30	0.043		0.051
F3		1.75			0.069	
F4		2.10			0.083	
G	10.80		11.10	0.425		0.437
H	14.70		15.20	0.279		0.598
L			12.20			0.480
L2			16.20			0.638
L3		18.0			0.709	
L5	3.95		4.15	0.156		0.163
L6		31.00			1.220	
O	4.00		4.10	0.157		0.161

- Cooling method : by conduction (C).
- Recommended torque value : 0.8 m.N
- Maximum torque value : 1 m.N

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTA3006CW	STTA3006CW	TO247	4.36g	30	Tube
STTA3006CP	STTA3006CP	SOT93	3.97g	30	Tube

- Epoxy meets UL94,V0

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics

© 1999 STMicroelectronics - Printed in Italy - All rights reserved.

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia
Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - U.S.A.

<http://www.st.com>